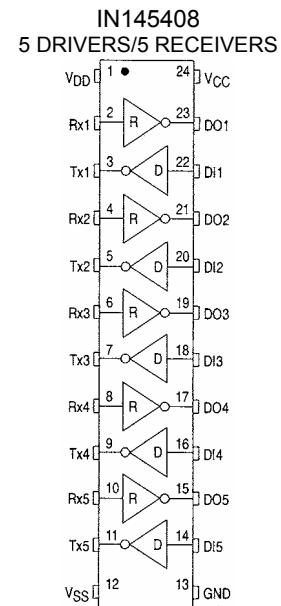
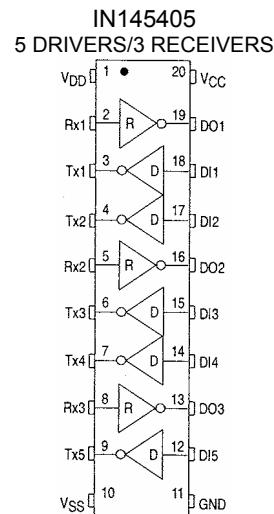
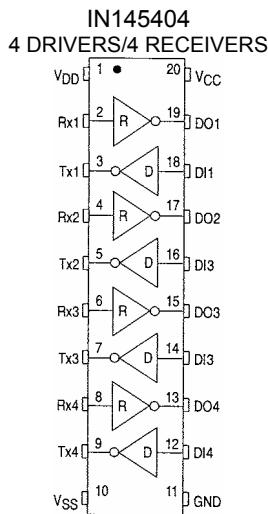
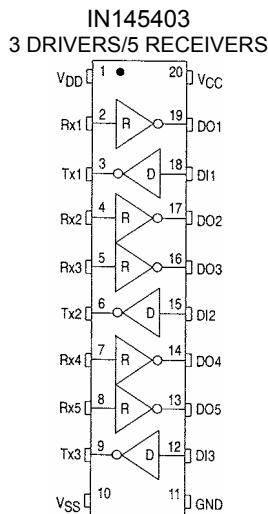


DRIVERS/RECEIVERS RS-232-E

These devices are silicon gate CMOS ICs that combine both the transmitter and receiver to fulfill the electrical specifications of EIA Standard 232-E and CCITT V.28. The drivers feature true TTL input compatibility, slew rate limiting outputs, 300 Ω power-off source impedance, and output typically switching to within 25% of the supply rails. The receivers can handle up to $\pm 25V$ while presenting 3 to 7 k Ω impedance. Hysteresis in the receivers aid in the reception of noisy signals. By combining both drivers and receivers in a single CMOS chip, these devices provide efficient, low-power solutions for both EIA-232-E and V.28 applications. These devices offer the following performance features:

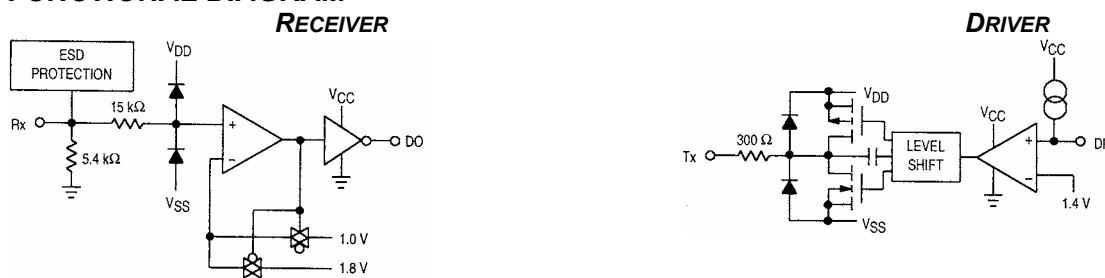
DRIVERS	RECEIVERS
<ul style="list-style-type: none"> ± 5 to ± 12 V Supply Range 300 Ω Power-Off Source Impedance Output Current Limiting TTL and CMOS Compatible Inputs Driver Slew Rate Range Limited to 30 V/μs Maximum 	<ul style="list-style-type: none"> $\pm 25V$ Input Range 3 to 7 kΩ Input Impedance 0.8V of Hysteresis for Enhanced Noise Immunity TTL and CMOS Compatible Outputs Available Driver/Receiver Combinations

Device	Drivers	Receivers	Figure	No. of Pins
IN145403	3	5	1	20
IN145404	4	4	2	20
IN145405	5	3	3	20
IN145408	5	5	4	24



IN145403 IN145404 IN145405 IN145408

FUNCTIONAL DIAGRAM



ABSOLUTE MAXIMUM RATINGS (Voltages referenced to GND, except where noted)

Rating	Symbol	Value	Unit
DC Supply Voltage ($V_{DD} \geq V_{CC}$)	V_{DD}	-0.5 to +13.5	V
	V_{SS}	+0.5 to -13.5	
	V_{CC}	-0.5 to + 6.0	
Input Voltage Range Rx1 - Rxn DI1 - DIn	V_{IR}	$V_{gg} - 15 \text{ to } V_{DO} + 15 \text{ to } V_{CC} + 15$	V
DC Current Drain per Pin	I	± 00	mA
Power Dissipation	P_D	1	W
Operating Temperature Range	T_A	-40 to +85	°C
Storage Temperature Range	T_{STG}	-85 to +150	°C

This device contains circuitry to protect the inputs and outputs against damage due to high static voltages or electric fields; however, it is advised that normal precautions be taken to avoid applications of any voltage higher than maximum rated voltages to this high impedance circuit.

For proper operation it is recommended that V_{out} and V_{in} be constrained to the ranges described as follows:

Digital I/O:

($GND \leq V_{DI} \leq V_{CC}$)

Receiver Outputs (DO):

($GND \leq V_{DO} \leq V_{CC}$)

EIA-232 I/O: Driver Outputs (Tx):

($V_{SS} \leq V_{Tx1-Txn} \leq V_{DD}$)

Receiver Inputs (Rx):

$V_{SS} - 15V \leq V_{Rx1-Rxn} \leq V_{DD} + 15V$

Reliability of operation is enhanced if unused outputs are tied off to an appropriate logic voltage level (e.g., either GND or V_{CC} for DI, and GND for Rx).

DC ELECTRICAL CHARACTERISTICS (All polarities referenced to GND=0V, $T_A = -40$ to +85°C)

Parameter	Symbol	Min	Typ	Max	Unit
DC Supply Voltage	V_{DD}	4.5	5 to 12	13.2	V
	V_{SS}	-4.5	-5 to -12	-13.2	
	V_{CC}	4.5	5	5.5	
Quiescent Supply Current (Outputs Unloaded, Inputs Low) $V_{DD} = +12V$ $V_{SS} = -12V$ $V_{CC} = +5V$	I_{DD} I_{SS} I_{CC}	-	425 -400 110	635 -600 200	nA



IN145403 IN145404 IN145405 IN145408

RECEIVER ELECTRICAL SPECIFICATIONS (Voltage polarities referenced to GND=0V, $V_{DD}=+12V$, $V_{SS}=-12V$, $T_A=-40$ to $+85^\circ C$, $V_{CC}=+5V \pm 10\%$)

Characteristic	Symbol	Min	Typ	Max	Unit
Input Turn-On Threshold Rx1 - Rxn $V_{DD}=V_{OL}$	V_{on}	1.35	1.8	2.35	V
Input Turn-Off Threshold Rx1 - Rxn $V_{DD}=V_{OH}$	V_{off}	0.75	1	1.25	V
Input Threshold Hysteresis $\Delta=V_{on}-V_{off}$	V_{hys}	0.6	0.8	—	V
Input Resistance ($V_{SS}-15V \leq V_{Rx1} - V_{Rxn} \leq (V_{DD}+15V)$)	R_{in}	3	5.4	7	kΩ
High Level Output Voltage $V_{RX}=-3$ to $-25V^*$ (D01-D0n)	$I_{out} = -20 \mu A$ $I_{out} = -1.0mA$	V_{OH}	4.9 3.8	4.9 4.3	- -
Low Level Output Voltage $V_{RX}=+3$ to $+25V$ (D01 - D0n)	$I_{out} = +2mA$ $I_{out} = +4 mA$	V_{OL}	- -	0.02 0.5	0.5 0.7

* This is the range of input voltages as specified by EIA-232-E to cause a receiver to be in the high or low.

DRIVER ELECTRICAL SPECIFICATIONS (Voltage Polarities Referenced to GND =0V, $V_{DD}=+12V$, $V_{SS}=-12V$, $T_A=-40$ to $+85^\circ C$, $V_{CC}=+5V \pm 10\%$)

Characteristic	Symbol	Min	Typ	Max	Unit
Digital Input Voltage	V_{IL}	-	-	0.8	V
Logic 0	V_{IH}	2	-	-	
Logic 1					
Input Current	I_{IL}	-	7	-	nA
$V_{DI}=GND$	I_{IH}	-	-	± 1.0	
$V_{DI}=V_{CC}$					
Output High Voltage	V_{OH}				
$V_{DI}=\text{Logic 0}, R_L = 3k\Omega$		3.5	3.9	-	V
$V_{DD}=+5.0V, V_{SS}=-5.0V$		4.3	4.7	-	
$V_{DD}=+6.0V, V_{SS}=-6.0V$		9.2	9.5	-	
$V_{DD}=+12.0V, V_{SS}=-12.0V$					
Output Low Voltage*	V_{OL}				
$V_{DI} = \text{Logic 1}, R_L = 3 k\Omega$		-4	-4.3	-	V
$V_{DD}=+5.0 V, V_{SS}=-5.0 V$		-4.5	-5.2	-	
$V_{DD}=+6.0 V, V_{SS}=-6.0 V$		-10	-10.3	-	
$V_{DD}=+12.0 V, V_{SS}=-12.0 V$					
Output Short Circuit Current	I_{SC}	-	$\pm 22 \pm 60$	$\pm 60 \pm 100$	mA
$V_{DD}=+12 V, V_{SS}=-12 V$					
Tx Shorted to GND					
Tx Shorted to $\pm 15V$					

* Voltage specifications are in terms of absolute values.

SWITCHING CHARACTERISTICS ($V_{CC}=+5V \pm 10\%$, $V_{DD}=+12V$, $V_{SS}=-12V$, $T_A=-40$ to $+85^\circ C$; See Figures 2 and 3)

Characteristic	Symbol	Min	Typ	Max	Unit
Drivers					
Propagation Delay Time Tx	t_{PLH}	-	500	1000	ns
Low-to-High $R_L=3k\Omega$, $C_L = 50 pF$	t_{PHL}	-	700	1000	
High-to-Low $R_L=3 k\Omega$, $C_L=50pF$					
Output Slew Rate					
Minimum Load					
$R_L=7 k\Omega$, $C_L=0 pF$ ($V_{DD}=6$ to $12 V$, $V_{SS}=-6$ to $-12 V$)	SR	-	± 6	± 30	V/ps
Maximum Load					
$R_L = 3 k\Omega$, $C_L = 2500 pF$ ($V_{DD}=12 V$, $V_{SS}=-12V$, $V_{CC}=5 V$)		4	-	-	
Receivers (CL = 50 pF)					
Propagation Delay Time Low-to-High	t_{PLH}	—	360	610	ns
High-to-Low	t_{PHL}	-	130	610	
Output Rise Time	t_r	-	250	400	ns
Output Fall Time	t_f	-	40	100	ns

